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Type: **Poster Presentation**

## Characterisation of sol-gel fabricated p-NiO/n-ZnO heterojunction

*Wednesday, 5 July 2017 17:10 (1h 50m)*

Zinc oxide nanorods were deposited on indium tin oxide (ITO) coated glass and silicon substrates, nickel oxide layer of 400 nm was deposited on the nanorods thereby forming a heterojunction between p-type nickel oxide and n-type zinc oxide thin films. The junction was characterised using x-ray diffraction (XRD), UV-visible spectroscopy, and scanning electron microscope. The current-voltage (I-V) characteristic of the junction was also investigated with and without ultra violet (UV) illumination.

**Apply to be considered for a student award (Yes / No)?**

Yes

**Level for award (Hons, MSc, PhD, N/A)?**

PhD

**Main supervisor (name and email) and his / her institution**

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**Would you like to submit a short paper for the Conference Proceedings (Yes / No)?**

Yes

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**Session Classification:** Poster Session 2

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